











CSD18540Q5B

SLPS488 - JUNE 2014

CSD18540Q5B 60V N-Channel NexFET™ Power MOSFETs

Features

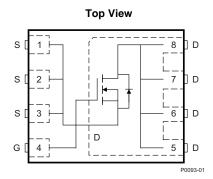
- Ultra-Low Qa and Qad
- Low Thermal Resistance
- Avalanche Rated
- Pb-Free Terminal Plating
- **RoHS Compliant**
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

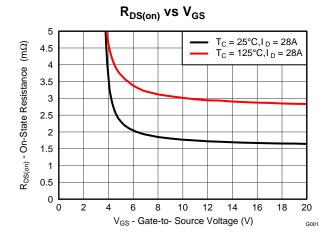
Applications

- DC-DC Conversion
- Secondary Side Synchronous Rectifier
- Isolated Converter Primary Side Switch
- Motor Control

3 Description

This 1.8 m Ω , 60 V, SON5x6 NexFETTM power MOSFET is designed to minimize losses in power conversion applications.





Product Summary

$T_A = 25^{\circ}$	С	TYPICAL VA	UNIT	
V_{DS}	Drain-to-Source Voltage	60	V	
Q_g	Gate Charge Total (10 V)	41	nC	
Q _{gd}	Gate Charge Gate-to-Drain	6.7	nC	
0	Drain-to-Source On Resistance	V _{GS} = 4.5 V	2.6	mΩ
R _{DS(on)}	Drain-to-Source On Resistance	V _{GS} = 10 V	1.8	mΩ
V _{GS(th)}	Threshold Voltage	1.9	V	

Ordering Information⁽¹⁾

Device	Qty	Media	Package	Ship
CSD18540Q5B	2500	13-Inch Reel	SON 5 × 6 mm	Tape and
CSD18540Q5BT	250	7-Inch Reel	Plastic Package	Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

	, 10001010 1110111111111111111111111111								
$T_A = 2$	5°C	VALUE	UNIT						
V_{DS}	Drain-to-Source Voltage	60	V						
V_{GS}	Gate-to-Source Voltage	±20	٧						
	Continuous Drain Current (Package limited)	100							
I _D	Continuous Drain Current (Silicon limited), $T_C = 25^{\circ}C$	221	Α						
	Continuous Drain Current ⁽¹⁾	28							
I _{DM}	Pulsed Drain Current, T _A = 25°C ⁽²⁾	400	Α						
n	Power Dissipation ⁽¹⁾	3.1	10/						
P _D	Power Dissipation, T _C = 25°C	195	W						
T _J , T _{stg}	Operating Junction and Storage Temperature Range	-55 to 150	°C						
E _{AS}	Avalanche Energy, single pulse $I_D = 80 \text{ A}, L = 0.1 \text{ mH}, R_G = 25 \Omega$	320	mJ						

- (1) Typical $R_{\theta JA} = 40^{\circ} C/W$ on a 1-inch 2 , 2-oz. Cu pad on a 0.06-inch thick FR4 PCB.
- (2) Max R_{θ,IC} = 0.8°C/W, Pulse duration ≤100 μs, duty cycle ≤1%



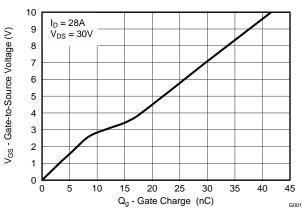






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4 Revision History

DATE	REVISION	NOTES
June 2014	*	Initial release.

Product Folder Links: CSD18540Q5B

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5 Specifications

5.1 Electrical Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
STATIC	CHARACTERISTICS				•	
BV _{DSS}	Drain-to-Source Voltage	V _{GS} = 0 V, I _D = 250 μA	60			V
I _{DSS}	Drain-to-Source Leakage Current	V _{GS} = 0 V, V _{DS} = 48 V			1	μΑ
I _{GSS}	Gate-to-Source Leakage Current	V _{DS} = 0 V, V _{GS} = 20 V			100	nA
V _{GS(th)}	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.5	1.9	2.3	V
D	Drain-to-Source On Resistance	$V_{GS} = 4.5 \text{ V}, I_D = 28 \text{ A}$		2.6	3.3	mΩ
R _{DS(on)}	Drain-to-Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 28 \text{ A}$		1.8	2.2	mΩ
9 _{fs}	Transconductance	$V_{DS} = 6 \text{ V}, I_D = 28 \text{ A}$		116		S
DYNAMI	C CHARACTERISTICS				•	
C _{iss}	Input Capacitance		3	3250	4230	рF
C _{oss}	Output Capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = 30 \text{ V}, f = 1 \text{ MHz}$		622	808	рF
C _{rss}	Reverse Transfer Capacitance			15	20	pF
R_{G}	Series Gate Resistance			8.0	1.6	Ω
Q_g	Gate Charge Total (4.5 V)			20	26	nC
Qg	Gate Charge Total (10 V)			41	53	nC
Q_{gd}	Gate Charge Gate-to-Drain	$V_{DS} = 30 \text{ V}, I_{D} = 28 \text{ A}$		6.7		nC
Q_{gs}	Gate Charge Gate-to-Source			8.8		nC
Q _{g(th)}	Gate Charge at V _{th}			6.3		nC
Q _{oss}	Output Charge	V _{DS} = 30 V, V _{GS} = 0 V		83		nC
t _{d(on)}	Turn On Delay Time			6		ns
t _r	Rise Time	V _{DS} = 30 V, V _{GS} = 10 V,		9		ns
t _{d(off)}	Turn Off Delay Time	$I_{DS} = 28 \text{ A}, R_G = 0 \Omega$		20		ns
t _f	Fall Time			3		ns
DIODE C	CHARACTERISTICS	· · · · · · · · · · · · · · · · · · ·				
V _{SD}	Diode Forward Voltage	I _{SD} = 28 A, V _{GS} = 0 V		8.0	1	V
Q _{rr}	Reverse Recovery Charge	V _{DS} = 30 V, I _F = 28 A,		145		nC
t _{rr}	Reverse Recovery Time	di/dt = 300 A/µs		82		ns

5.2 Thermal Information

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$

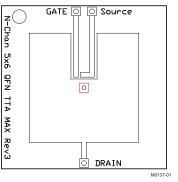
	THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance ⁽¹⁾			8.0	°C/W
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance ⁽¹⁾⁽²⁾			50	C/VV

⁽¹⁾ R_{0JC} is determined with the device mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inches × 1.5-inches (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB. R_{0JC} is specified by design, whereas R_{0JA} is determined by the user's board design.

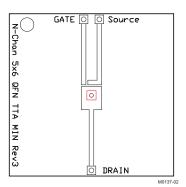
(2) Device mounted on FR4 material with 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu.

Product Folder Links: CSD18540Q5B

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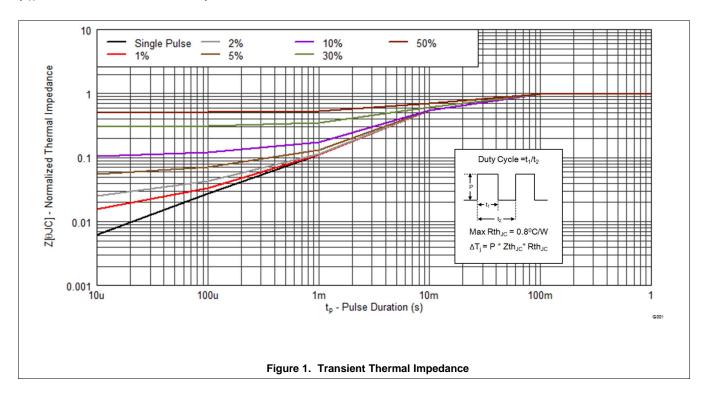
Max $R_{\theta JA} = 50^{\circ} C/W$ when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max $R_{\theta JA} = 125^{\circ} C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

5.3 Typical MOSFET Characteristics

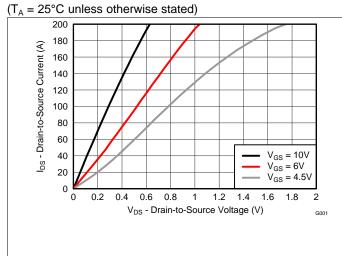
(T_A = 25°C unless otherwise stated)





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Typical MOSFET Characteristics (continued)



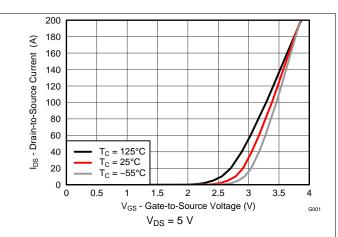
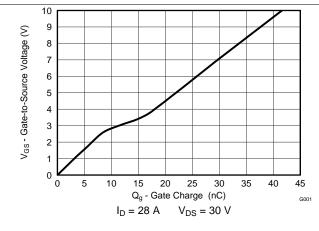


Figure 2. Saturation Characteristics





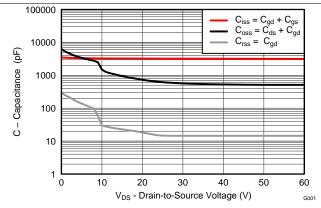


Figure 4. Gate Charge

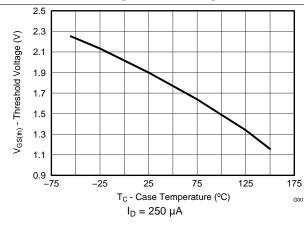


Figure 6. Threshold Voltage vs Temperature

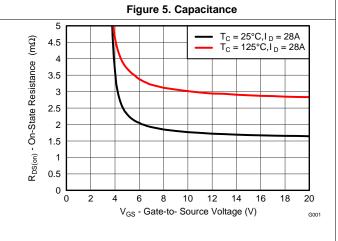


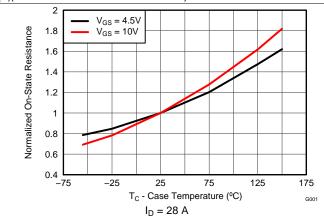
Figure 7. On-State Resistance vs Gate-to-Source Voltage

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Typical MOSFET Characteristics (continued)

(T_A = 25°C unless otherwise stated)



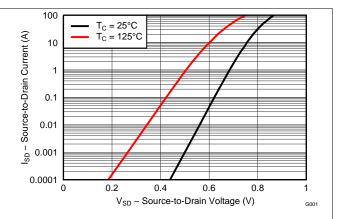
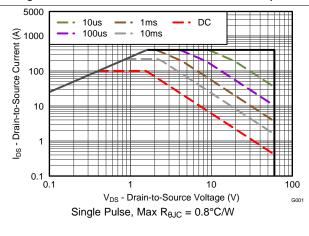


Figure 8. Normalized On-State Resistance vs Temperature

Figure 9. Typical Diode Forward Voltage



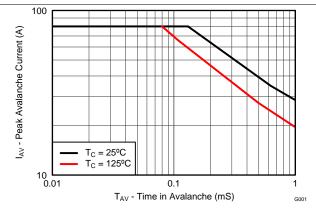


Figure 10. Maximum Safe Operating Area

Figure 11. Single Pulse Unclamped Inductive Switching

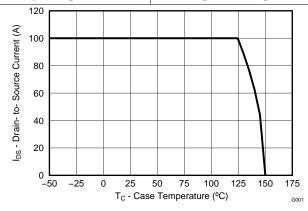


Figure 12. Maximum Drain Current vs Temperature



6 Device and Documentation Support

6.1 Trademarks

NexFET is a trademark of Texas Instruments.

6.2 Electrostatic Discharge Caution



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

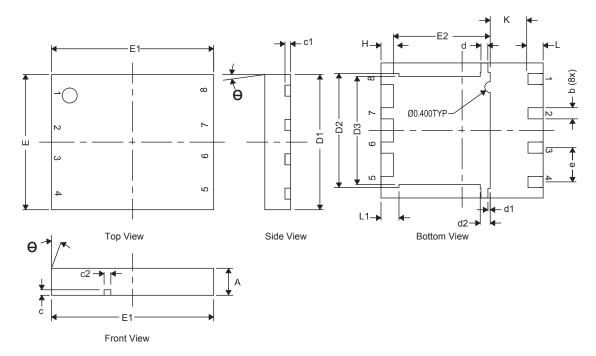
Product Folder Links: CSD18540Q5B



7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 Q5B Package Dimensions



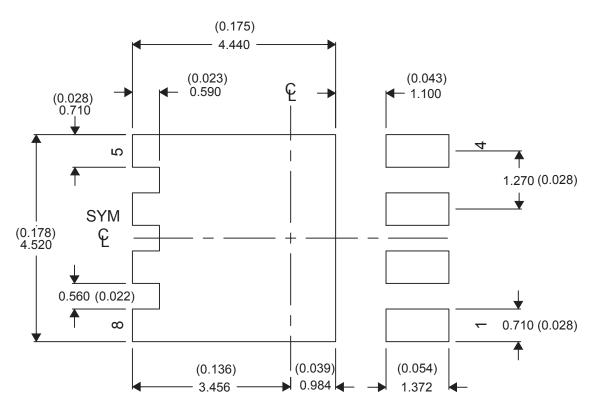
DIM	MILLIMETERS							
DIM	MIN	NOM	MAX					
A	0.80	1.00	1.05					
b	0.36	0.41	0.46					
С	0.15	0.20	0.25					
c1	0.15	0.20	0.25					
c2	0.20	0.25	0.30					
D1	4.90	5.00	5.10					
D2	4.12	4.22	4.32					
D3	3.90	4.00	4.10					
d	0.20	0.25	0.30					
d1		0.085 TYP						
d2	0.319	0.369	0.419					
Е	4.90	5.00	5.10					
E1	5.90	6.00	6.10					
E2	3.48	3.58	3.68					
е		1.27 TYP						
Н	0.36	0.46	0.56					
L	0.46	0.56	0.66					
L1	0.57	0.67	0.77					
θ	0°	_	_					
К		1.40 TYP						

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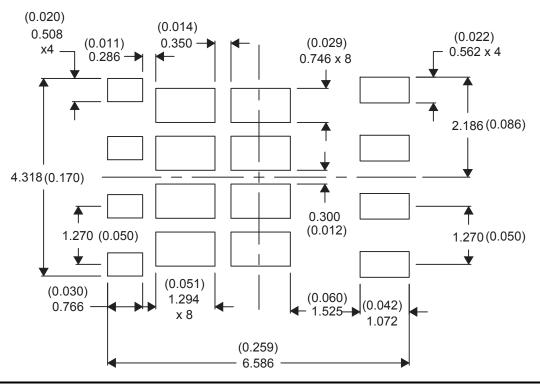
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7.2 Recommended PCB Pattern



For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

7.3 Recommended Stencil Pattern

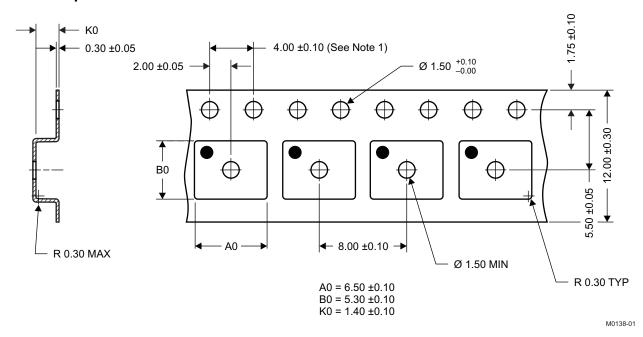


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7.4 Q5B Tape and Reel Information



Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1 mm in 100 mm, noncumulative over 250 mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified).
- 5. A0 and B0 measured on a plane 0.3 mm above the bottom of the pocket

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PACKAGE OPTION ADDENDUM

6-Apr-2015

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CSD18540Q5B	ACTIVE	VSON-CLIP	DNK	8	2500	Pb-Free (RoHS Exempt)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-55 to 150	CSD18540	Samples
CSD18540Q5BT	ACTIVE	VSON-CLIP	DNK	8	250	Pb-Free (RoHS Exempt)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-55 to 150	CSD18540	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

6-Apr-2015

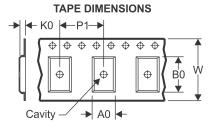
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual bas
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PACKAGE MATERIALS INFORMATION

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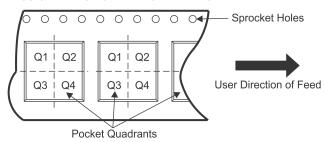
TAPE AND REEL INFORMATION





_		
		Dimension designed to accommodate the component width
		Dimension designed to accommodate the component length
		Dimension designed to accommodate the component thickness
	W	Overall width of the carrier tape
ſ	P1	Pitch between successive cavity centers

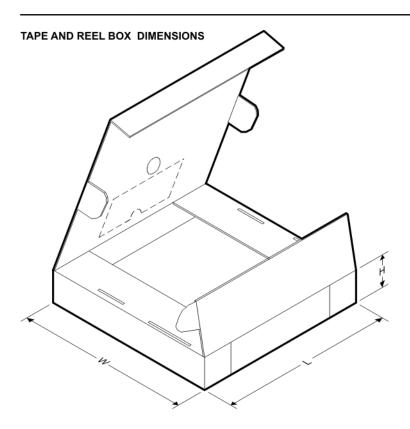
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CSD18540Q5B	VSON- CLIP	DNK	8	2500	330.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1
CSD18540Q5BT	VSON- CLIP	DNK	8	250	180.0	12.4	6.3	5.3	1.2	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CSD18540Q5B	VSON-CLIP	DNK	8	2500	367.0	367.0	35.0
CSD18540Q5BT	VSON-CLIP	DNK	8	250	210.0	185.0	35.0

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